

PD20010-E Information


For Reference Only

Part Number [PD20010-E](#)
Manufacturer STMicroelectronics
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - RF](#)
Description TRANS RF N-CH FET POWERSO-10RF
Package PowerSO-10RF Exposed Bottom Pad (2 Formed Leads)
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


[Request a Quote](#)
Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


PD20010-E Specifications

Manufacturer Part Number	PD20010-E
Manufacturer	STMicroelectronics
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - RF
Package	PowerSO-10RF Exposed Bottom Pad (2 Formed Leads)
Series	-
Transistor Type	LDMOS
Frequency	2GHz
Gain	11dB
Voltage - Test	13.6V
Current Rating	5A
Noise Figure	-
Current - Test	150mA
Power - Output	10W
Voltage - Rated	40V
Package / Case	PowerSO-10RF Exposed Bottom Pad (2 Formed Leads)
Supplier Device Package	PowerSO-10RF (Formed Lead)

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PD20010-E Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

PD20010-E Payment Methods



PD20010-E Shipping Methods



If you have any question about PD20010-E, please do not hesitate to contact us!

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